

Optically Coupled Isolator

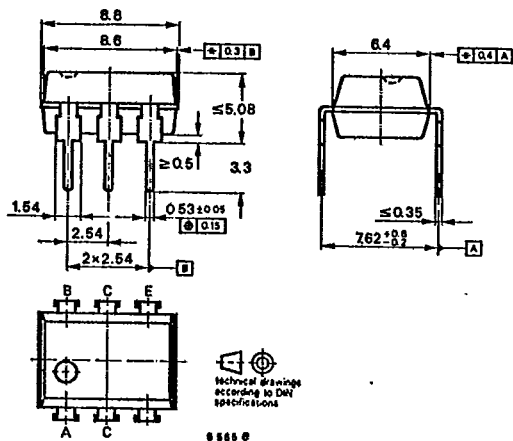
Construction: Emitter: GaAs IR Emitting Diode  
Detector: Silicon NPN Epitaxial Planar Phototransistor

Applications: Galvanically separated circuits,  
non-interacting switches

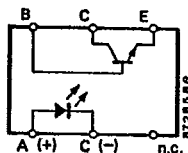
Features:

- DC isolation test voltage  $V_{is}$  4.4 kV
- Low coupling capacity  $C_K$  typ. 0.3 pF
- Test class 25/100/21 DIN 40045
- Current transfer ratio in groups selected
- Low temperature coefficient of CTR

Dimensions in mm



Pin connections



Plastic case  
DIP 6  
Weight max. 0.7 g

Absolute maximum ratings

Emitter

Reverse voltage	$V_R$	5	V
Forward current	$I_F$	50	mA
Forward surge current	$I_{FSM}$	1.5	A
$\frac{I_p}{T} \leq 10 \mu s$			
Power dissipation	$P_V$	120	mW
$T_{amb} \leq 25 \text{ }^\circ\text{C}$			
Junction temperature	$T_j$	125	$^\circ\text{C}$

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## Detector

Collector base voltage	$V_{CBO}$	50	V
Collector emitter voltage	$V_{CEO}$	32	V
Emitter collector voltage	$V_{ECO}$	7	V
Collector current	$I_C$	50	mA
Peak collector current			
$\frac{t_p}{T} = 0.5, t_p \leq 10 \text{ ms}$	$I_{CM}$	100	mA
Power dissipation			
$T_{amb} = 25^\circ\text{C}$	$P_V$	130	mW
Junction temperature	$T_J$	125	$^\circ\text{C}$

## Coupled device

DC isolation test voltage			
$t = 1 \text{ min.}$	$V_{is}^{1)}$	4.4	V
Total power dissipation			
$T_{amb} \leq 25^\circ\text{C}$	$P_{tot}$	250	mW
Ambient temperature range	$T_{amb}$	-55...+100	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55...+125	$^\circ\text{C}$
Soldering temperature			
2 mm from case, $t \leq 10 \text{ s}$	$T_{sd}$	260	$^\circ\text{C}$

## Electrical characteristics

 $T_{amb} = 25^\circ\text{C}$ 

Min. Typ. Max.

## Emitter

Forward voltage			
$I_F = 50 \text{ mA}$	$V_F$	1.25	1.6 V
Breakdown voltage			
$I_R = 100 \mu\text{A}$	$V_{(BR)}$	5	V
Junction capacitance			
$V_R = 0, f = 1 \text{ MHz}$	$C_j$	50	pF

## Detector

Collector emitter breakdown voltage			
$I_C = 1 \text{ mA}$	$V_{(BR)CEO}$	32	V
Collector dark current			
$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	$I_{CEO}$		200 nA
$V_{CE} = 10 \text{ V}, I_F = 0, E = 0$	$I_{CEO}$		50 nA
$V_{CB} = 10 \text{ V}, I_F = 0, E = 0$	$I_{CBO}$		20 nA
Collector emitter saturation voltage			
$I_C = 1 \text{ mA}, I_F = 10 \text{ mA}$	$V_{CEsat}$	0.3	V

<sup>1)</sup> related to standard climate 23/50 DIN 50014

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Coupled device			Min.	Typ.	Max.	
DC isolation test voltage						
$t = 1 \text{ min}$		$V_{is}^{1)}$	4.4			kV
Isolation resistance						
$V_{IO} = 1 \text{ kV}$ , 40% relative humidity		$R_{is}^{1)}$		$10^{12}$		$\Omega$
Collector current						
$V_{CE} = 5 \text{ V}$ , $I_F = 10 \text{ mA}$	K 102 P1	$I_C$	2	6		mA
	K 102 P2	$I_C$	4		8	mA
	K 102 P3	$I_C$	6.2		12.5	mA
$I_F = 2 \text{ mA}$	K 102 P2	$I_C$	0.4		1	mA
	K 102 P3	$I_C$	0.5		1.2	mA
Current transfer ratio						
$V_{CE} = 5 \text{ V}$ , $I_F = 10 \text{ mA}$	K 102 P1	CTR	20	60		%
	K 102 P2	CTR	40		80	%
	K 102 P3	CTR	62		125	%
$I_F = 2 \text{ mA}$	K 102 P2	CTR	20		50	%
	K 102 P3	CTR	25		60	%
Cut-off frequency						
$V_{CE} = 5 \text{ V}$ , $I_F = 10 \text{ mA}$ , $R_L = 100 \Omega$		$f_0$		110		kHz
Coupling capacitance						
$f = 1 \text{ MHz}$		$C_k$		0.3		pF
Switching characteristics						
$V_S = 5 \text{ V}$ , $I_C = 5 \text{ mA}$ , $R_L = 100 \Omega$ , see Fig. 1						
Delay time		$t_d$		4.0		$\mu\text{s}$
Rise time		$t_r$		7.0		$\mu\text{s}$
Turn-on time		$t_{on}$		11.0		$\mu\text{s}$
Storage time		$t_s$		0.3		$\mu\text{s}$
Fall time		$t_f$		6.7		$\mu\text{s}$
Turn-off time		$t_{off}$		7.0		$\mu\text{s}$
$V_S = 5 \text{ V}$ , $I_F = 10 \text{ mA}$ , $R_L = 1 \text{ k}\Omega$ , see Fig. 2						
Turn-on time		$t_{on}$		25		$\mu\text{s}$
Turn-off time		$t_{off}$		42.5		$\mu\text{s}$

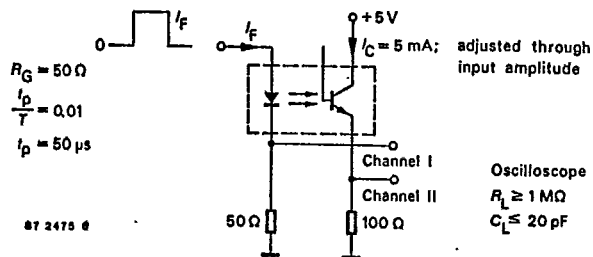


Fig. 1 Test circuit, non saturated operation

<sup>1)</sup> related to standard climate 23/50 DIN 50014

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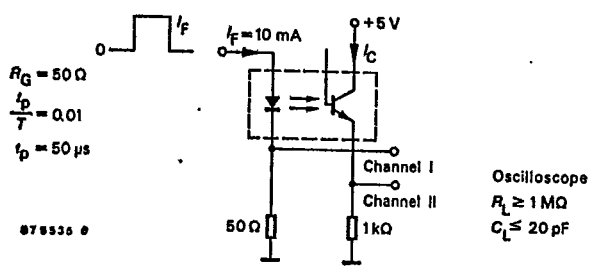
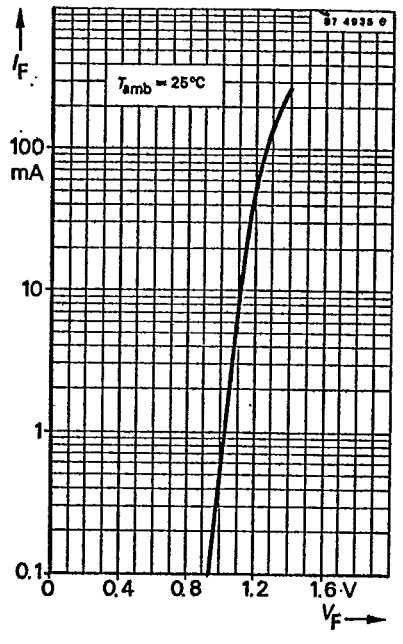
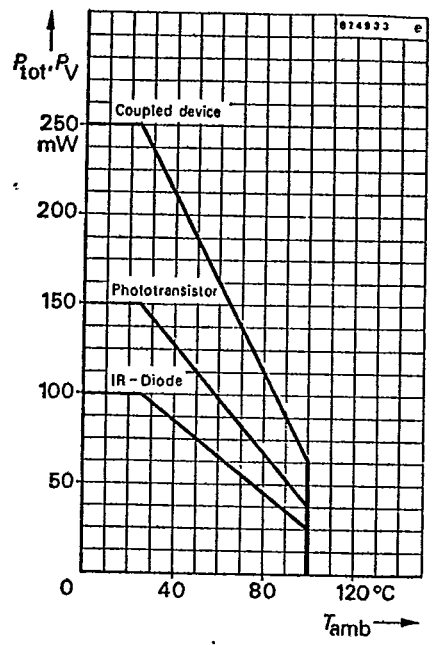
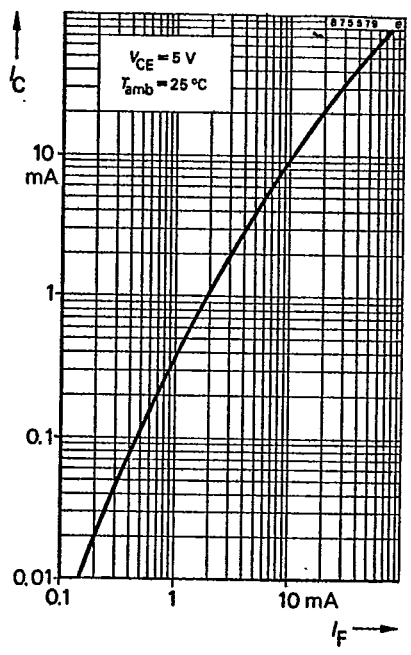
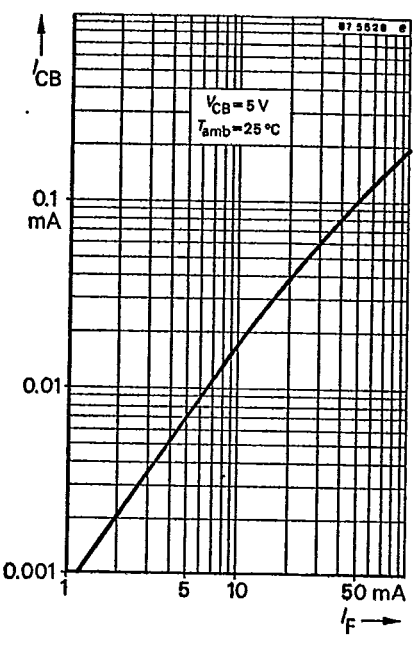
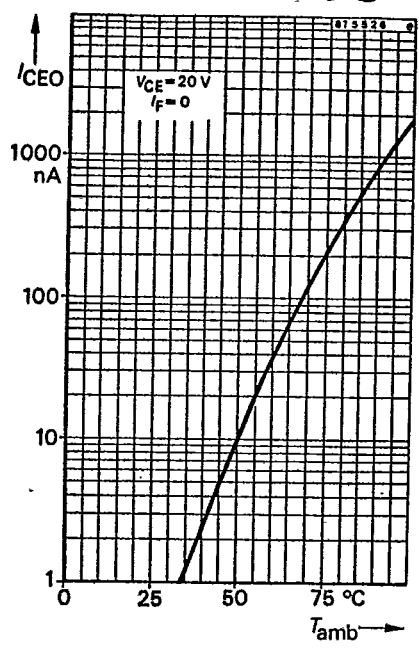
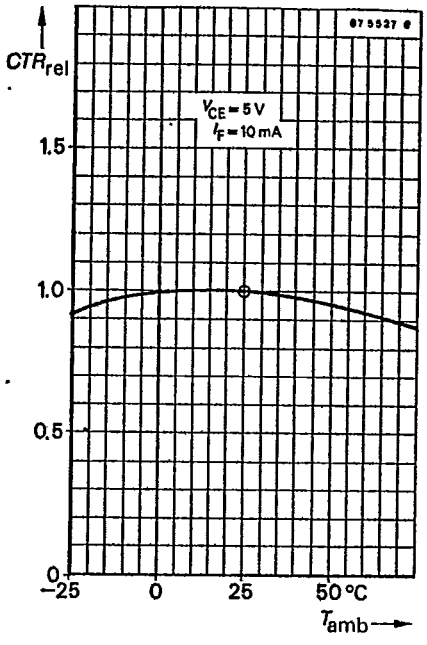


Fig. 2 Test circuit, saturated operation



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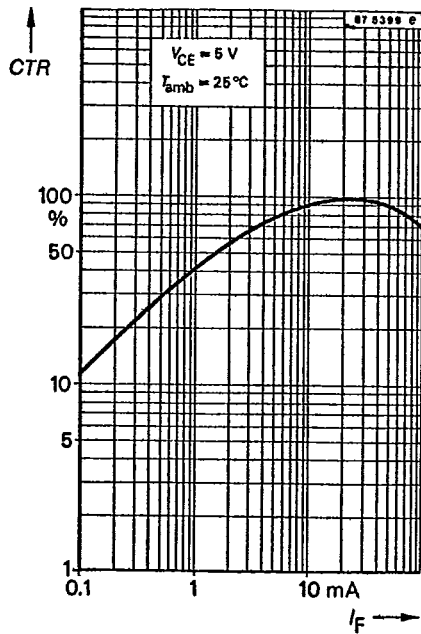
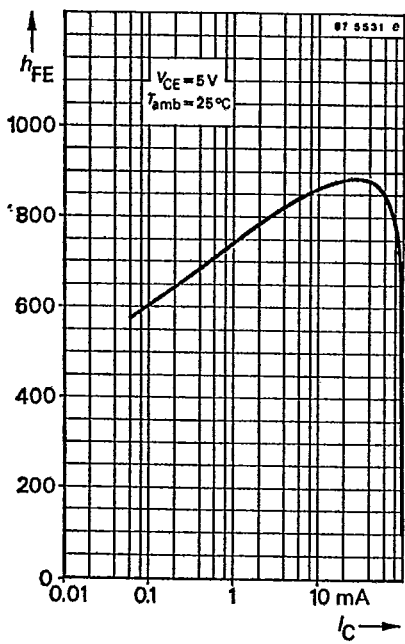
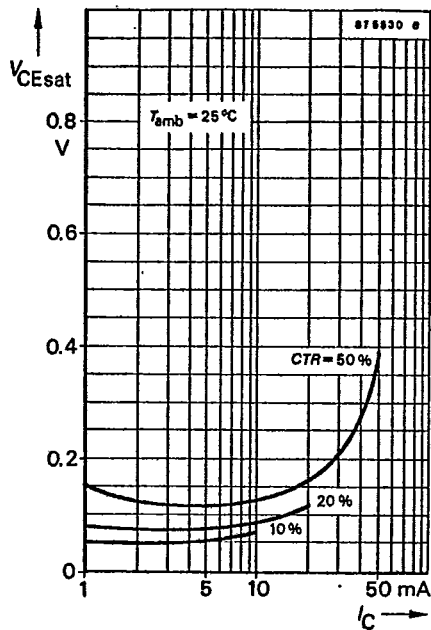
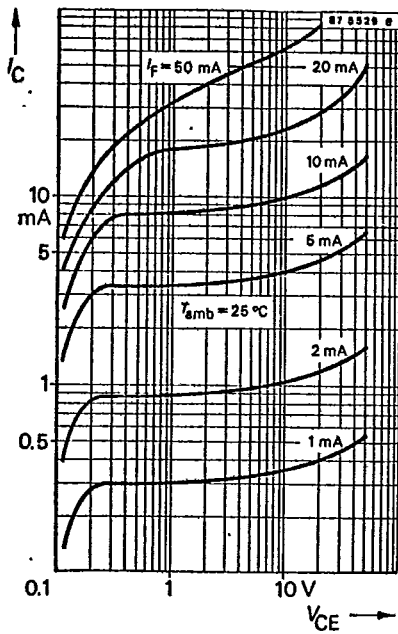
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